

Application No.: 09/940,885

Docket No.: 500.40562X00

**AMENDMENTS TO THE ABSTRACT**

Please enter the replacement Abstract as listed on the following clean  
page:

ABSTRACT OF THE DISCLOSURE

~~When an~~ An active matrix display device using a thin film transistor as a switching element in the displaying portion or driving portion is characterized in that said thin film transistor ~~comprises~~ includes an insulating substrate on which a gate electrode, a gate insulating film, a semiconductor layer, a drain electrode, a source electrode and a passivation film are successively laminated, ~~and~~. The thin film transistor is further characterized such that the surface portion of the semiconductor layer on the side of the passivation film is porous, which enables the device ~~can to~~ be stably driven with a low off-current even in the case of disposing an organic passivation film and a picture element electrode on the thin film transistor.

**AMENDMENTS TO THE DRAWINGS**

The attached two (2) replacement sheets include formal changes effected with regard to Figs. 7 and 8 of the drawings. Specifically, the labeled reference character 710 in three instances in Fig. 7 was corrected to 701. This correction is consistent with the same reference character 701 shown elsewhere in Figs. 7 and 8 which pertains to the same illustrated component. This is also consistent with the related description thereof such as on page 26 of the original Specification (or on page 23 of the Substitute Specification).

Additional minor corrections were effected in Figs. 7 and 8 regarding the line locators pertaining to the reference characters 105 and 107 to thereby maintain consistency throughout the various views with regard to Figs. 7 and 8, consistent with that originally disclosed.

**Attachments:**

**Replacement sheets directed to Figs. 7 and 8 of the drawings;**

**Annotated sheets showing changes made to Figs. 7 and 8 in red.**